

## IGBT MODULE ( S-Series )

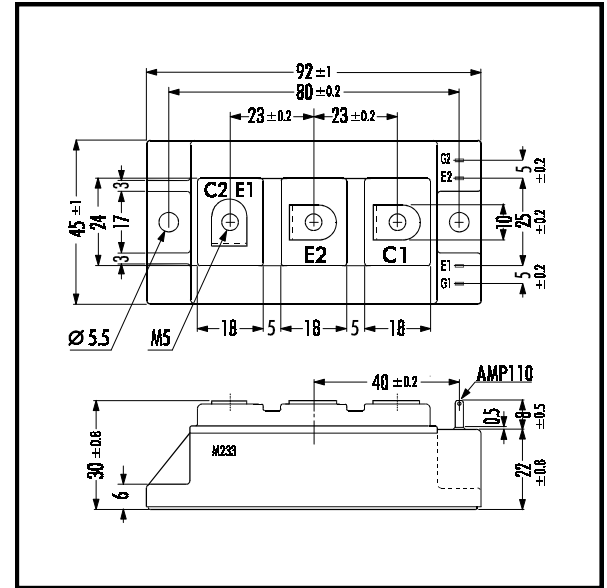
### ■ Features

- NPT-Technology
- Square SC SOA at  $10 \times I_C$
- High Short Circuit Withstand-Capability
- Small Temperature Dependence of the Turn-Off Switching Loss
- Low Losses And Soft Switching

### ■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

### ■ Outline Drawing



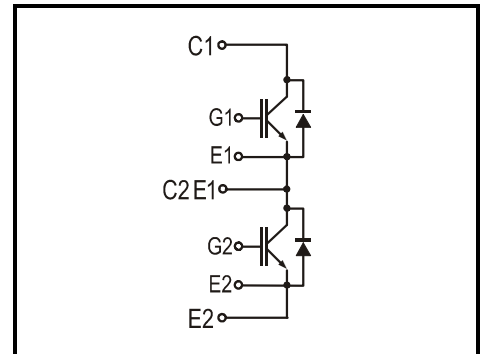
### ■ Maximum Ratings and Characteristics

#### • Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

Items	Symbols	Ratings	Units	
Collector-Emitter Voltage	$V_{CES}$	1200	V	
Gate -Emitter Voltage	$V_{GES}$	$\pm 20$		
Collector Current	Continuous	$I_C$	200 / 150	A
	1ms	$I_{C \text{ PULSE}}$	400 / 300	
	Continuous	$-I_C$	150	
	1ms	$-I_{C \text{ PULSE}}$	300	
Max. Power Dissipation	$P_C$	1000	W	
Operating Temperature	$T_j$	+150	$^\circ\text{C}$	
Storage Temperature	$T_{stg}$	-40 ~ +125		
Isolation Voltage *1	A.C. 1min.	$V_{is}$	2500	V
Screw Torque	Mounting *2	3.5	Nm	
	Terminals *2	3.5		

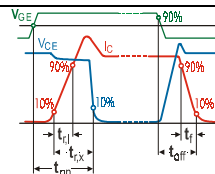
Note: 1\*: All Terminals should be connected together when isolation test will be done.  
2\*: Recommendable Value, 2.5 - 3.5 Nm (M5)

### ■ Equivalent Circuit



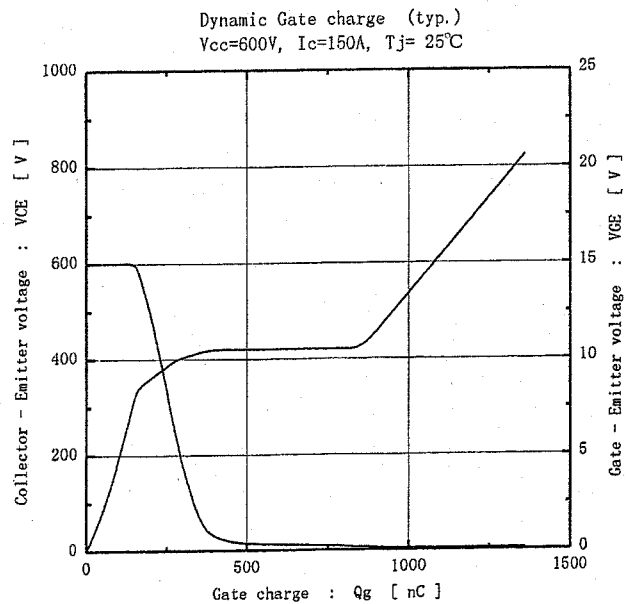
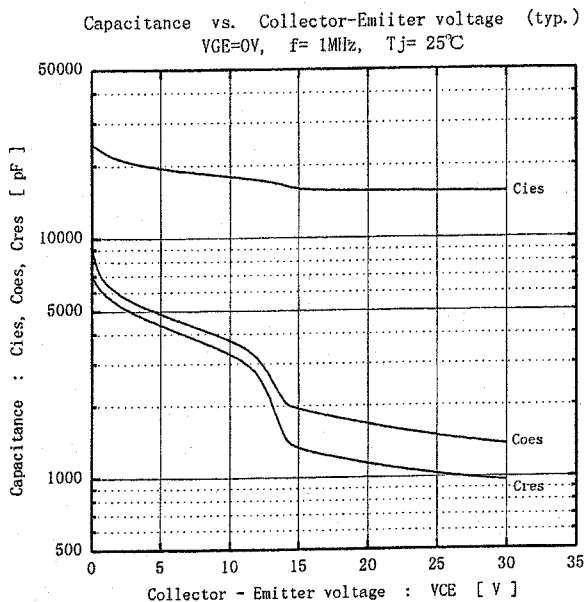
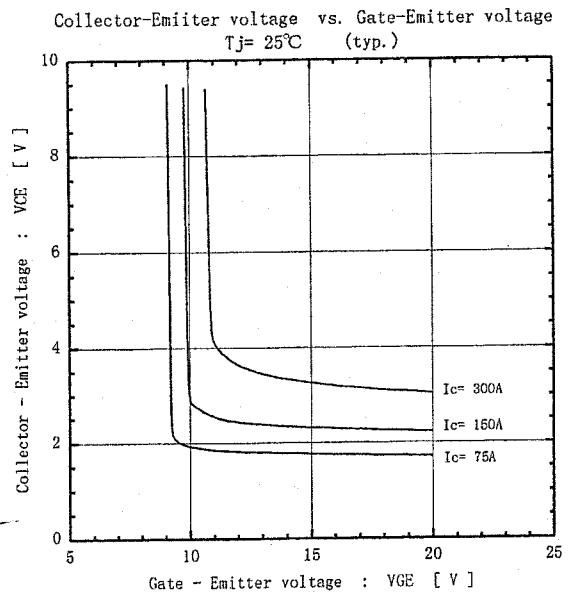
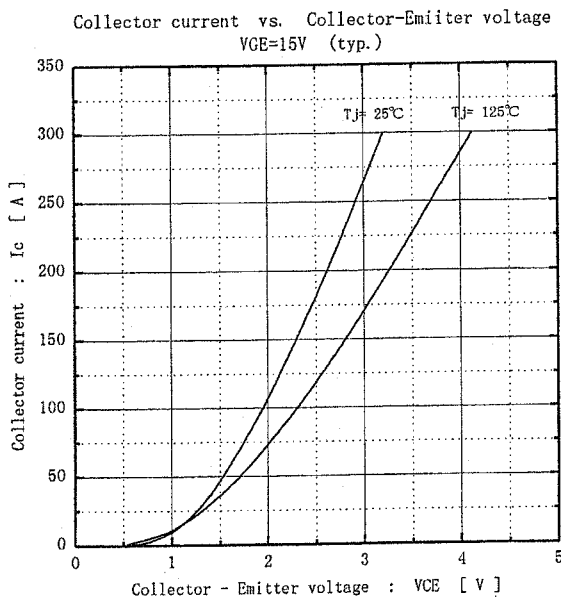
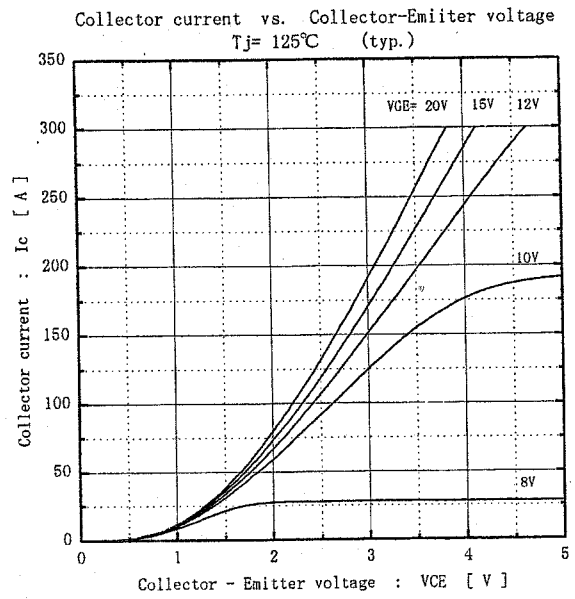
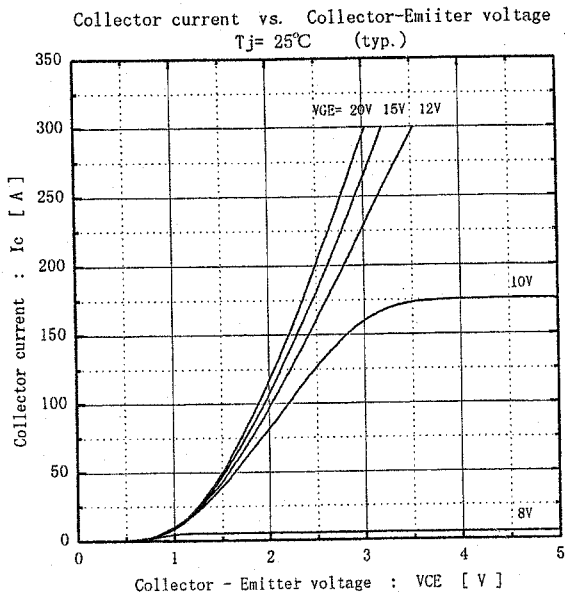
#### • Electrical Characteristics ( at $T_j=25^\circ\text{C}$ )

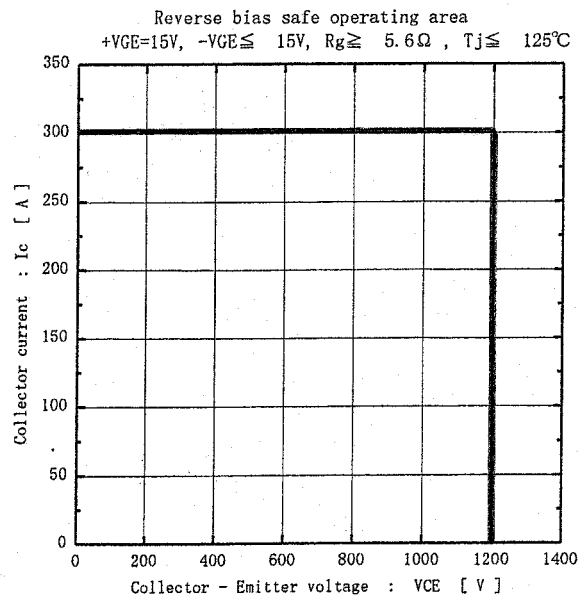
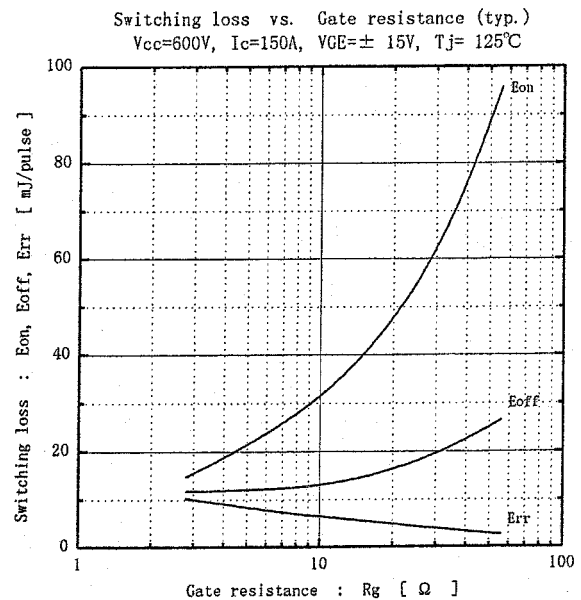
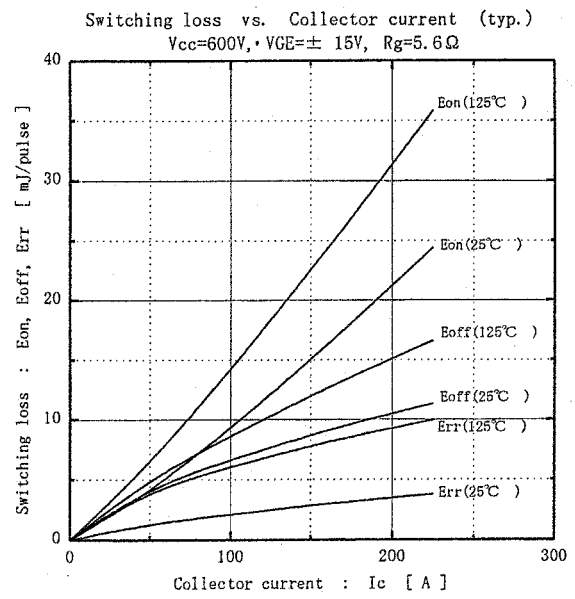
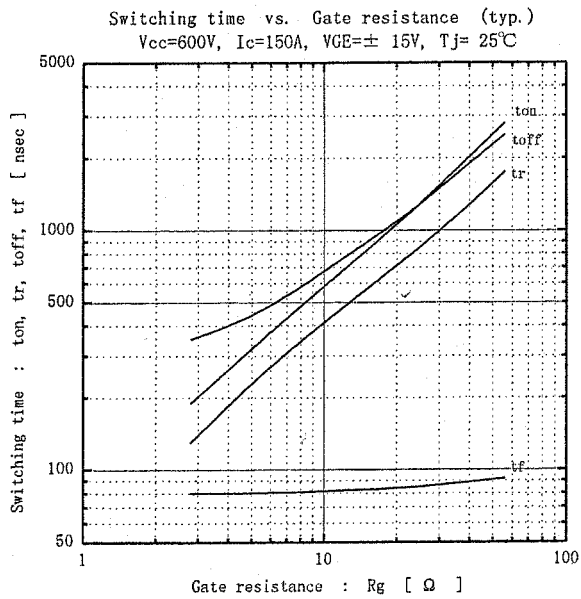
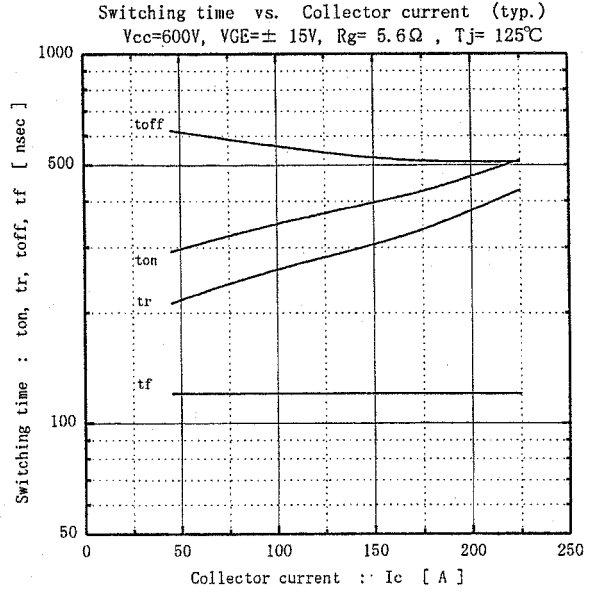
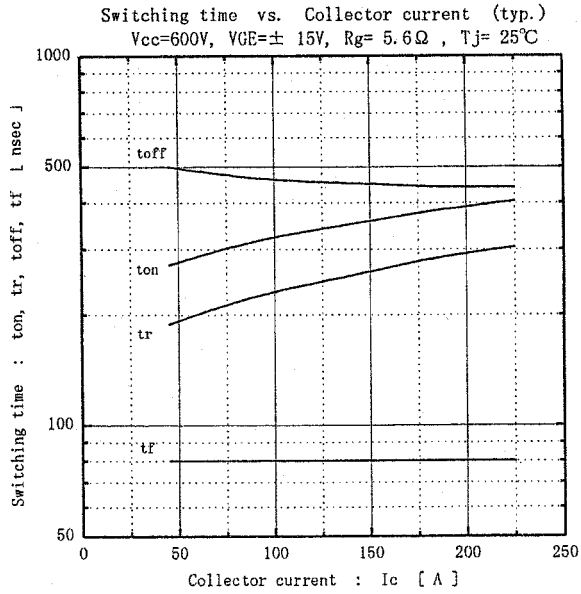
Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	$I_{CES}$	$V_{GE}=0V$ $V_{CE}=1200V$			2.0	mA
Gate-Emitter Leakage Current	$I_{GES}$	$V_{CE}=0V$ $V_{GE}=\pm 20V$			400	nA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=20V$ $I_C=150mA$	5.5	7.2	8.5	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE}=15V$ $I_C=150A$		2.3	2.6	
Input Capacitance	$C_{ies}$	$V_{GE}=0V$		18'000		pF
Output Capacitance	$C_{oes}$	$V_{CE}=10V$		3'750		
Reverse Transfer Capacitance	$C_{res}$	$f=1MHz$		3'300		
Turn-on Time	$t_{ON}$	$V_{CC}=600V$		0.35	1.2	$\mu\text{s}$
	$t_{r,x}$	$I_C=150A$		0.25	0.6	
	$t_{r,i}$	$V_{GE}=\pm 15V$		0.10		
Turn-off Time	$t_{OFF}$	$R_G=5.6\Omega$		0.45	1.0	$\mu\text{s}$
	$t_f$	Inductive Load		0.08	0.3	
Diode Forward On-Voltage	$V_F$	$I_F=150A$ ; $V_{GE}=0V$	$T_j=25^\circ\text{C}$	2.3	3.0	V
Reverse Recovery Time	$t_{rr}$	$I_F=150A$	$T_j=125^\circ\text{C}$	2.0		



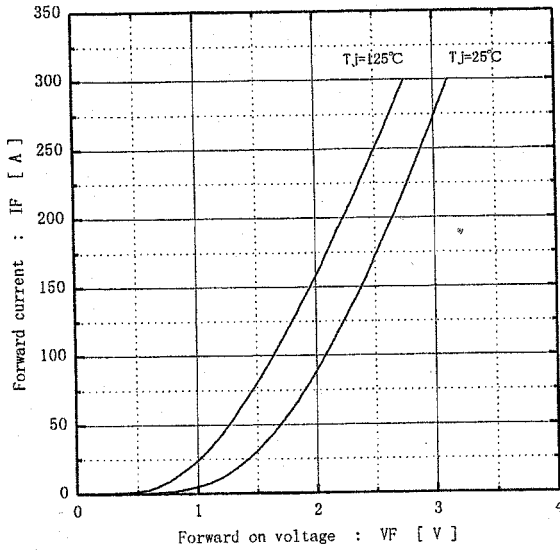
#### • Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	$R_{th(j-c)}$	IGBT			0.125	$^\circ\text{C/W}$
	$R_{th(j-c)}$	Diode			0.260	
	$R_{th(c-f)}$	With Thermal Compound		0.025		

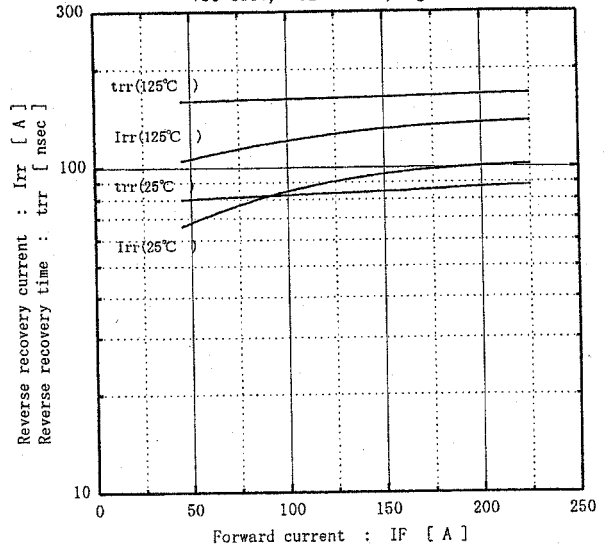




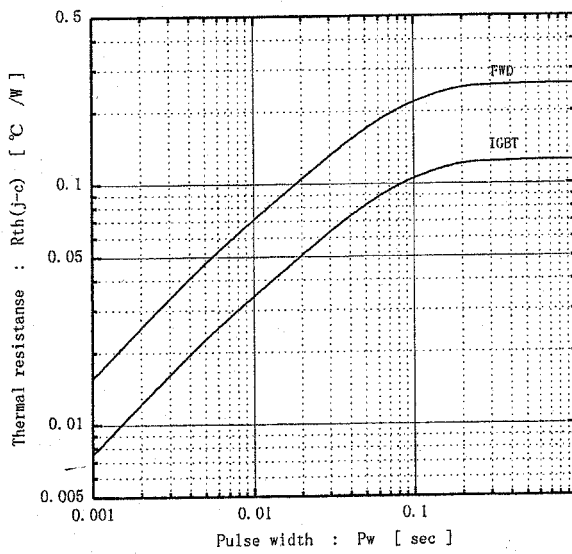
Forward current vs. Forward on voltage (typ.)



Reverse recovery characteristics (typ.)  
Vcc=600V, VGE=±15V, Rg=5.6Ω



Transient thermal resistance



This datasheet has been downloaded from:

[www.DatasheetCatalog.com](http://www.DatasheetCatalog.com)

Datasheets for electronic components.



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.